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P-Channel 100 V (D-S) MOSFET

DESCRIPTION

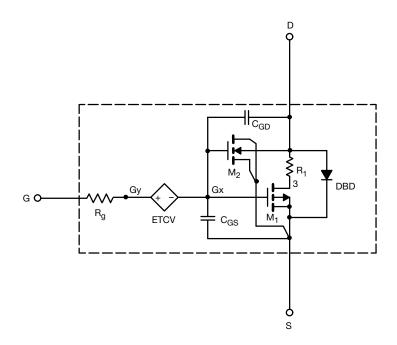
The attached SPICE model describes the typical electrical characteristics of the p-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched C_{gd} model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

CHARACTERISTICS

- P-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- · Model the Gate Charge

SUBCIRCUIT MODEL SCHEMATIC



Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	3.2	-	V
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = -10 \text{ V}, I_D = -6 \text{ A}$	0.114	0.115	Ω
		$V_{GS} = -7.5 \text{ V}, I_D = -6 \text{ A}$	0.117	0.117	
Forward Transconductance ^a	9 _{fs}	V _{DS} = -15 V, I _D = -6 A	18	18	S
Diode Forward Voltage	V_{SD}	I _S = -5 A	-0.84	-0.85	V
Dynamic ^b					
Input Capacitance	C _{iss}	V _{DS} = -50 V, V _{GS} = 0 V, f = 1 MHz	2130	2110	pF
Output Capacitance	Coss		106	105	
Reverse Transfer Capacitance	C _{rss}		59	58	
Total Gate Charge	Qg	$V_{DS} = -50 \text{ V}, V_{GS} = -10 \text{ V}, I_D = -6.7 \text{ A}$	33	40	- nC
		$V_{DS} = -50 \text{ V}, V_{GS} = -6 \text{ V}, I_D = -6.7 \text{ A}$	22	24	
Gate-Source Charge	Q_{gs}		12.5	12.5	
Gate-Drain Charge	Q_{gd}		6.7	6.7	

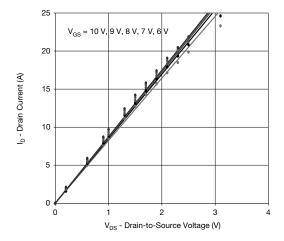
Notes

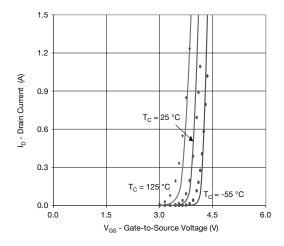
- a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

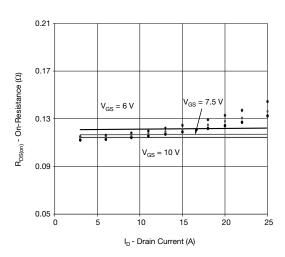
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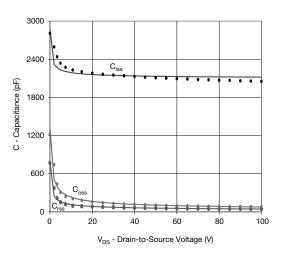
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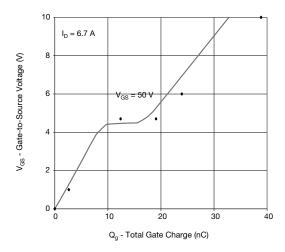
COMPARISON OF MODEL WITH MEASURED DATA ($T_J = 25$ °C, unless otherwise noted)

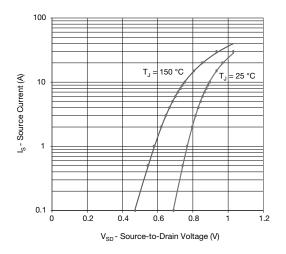












Note

Dots and squares represent measured data.
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Revision: 02-Oct-12 Document Number: 91000